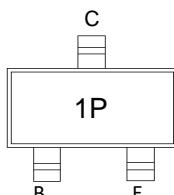
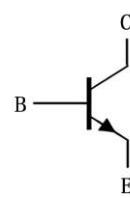
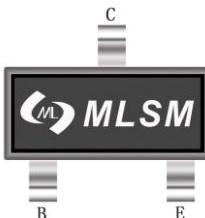


## Features

- Epitaxial planar die construction
- Complementary PNP Type available(MMBT2907A)



Marking and pin assignment



Halogen-Free

## Maximum Ratings (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	75	V
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>c</sub>	Collector Current	600	mA
P <sub>c</sub>	Collector Power Dissipation	300	mW
R <sub>θJA</sub>	Thermal Resistance Junction to Ambient	417	°C/W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55~+150	°C

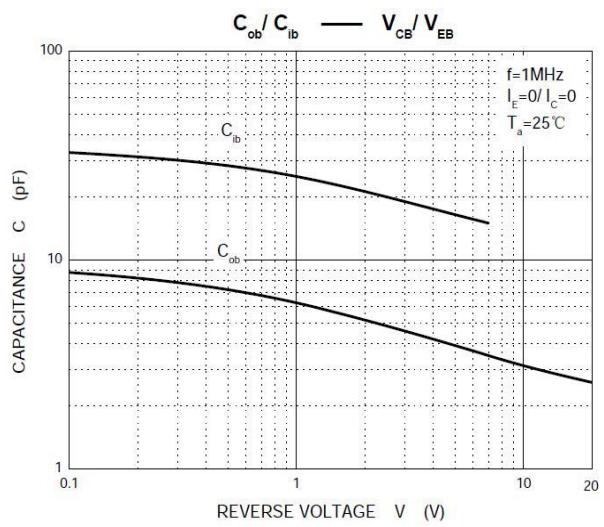
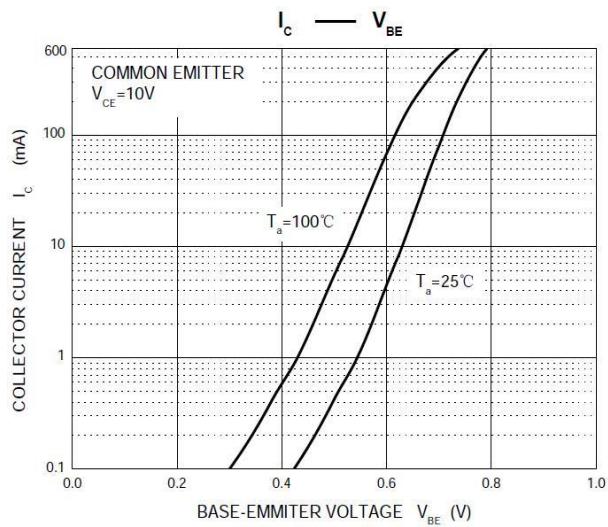
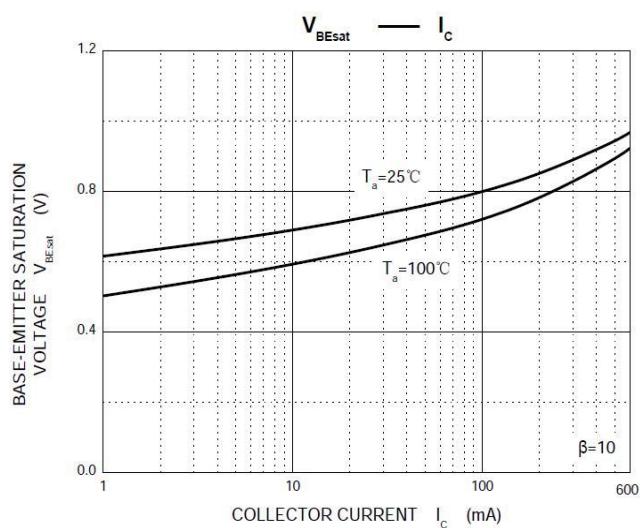
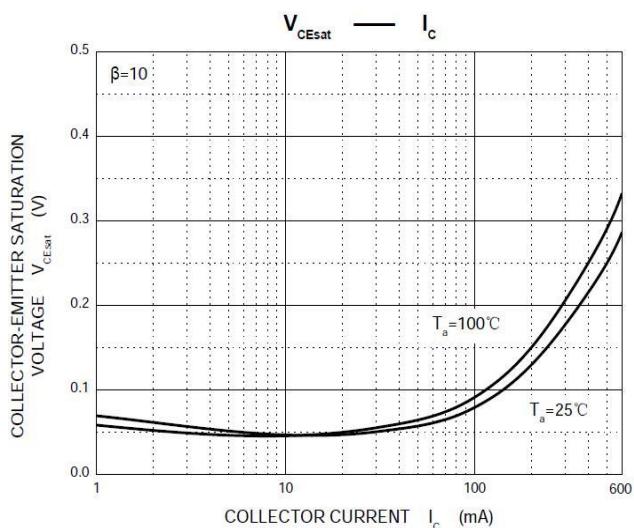
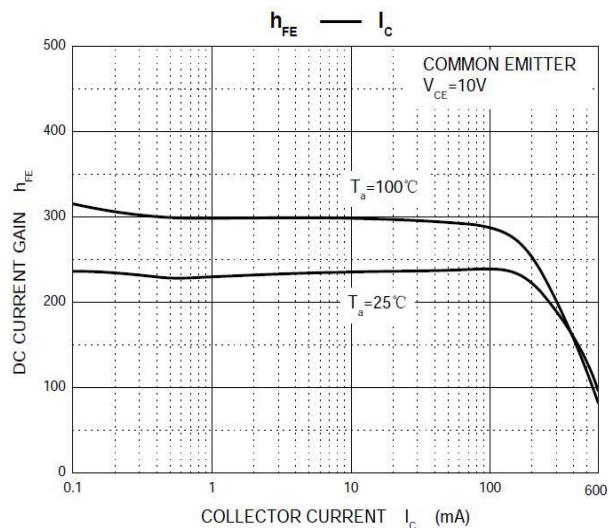
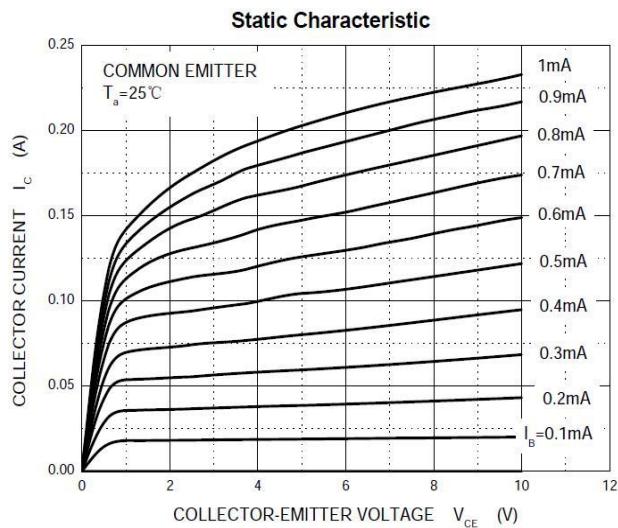
## Electrical Characteristics (Ta=25°C unless otherwise specified)

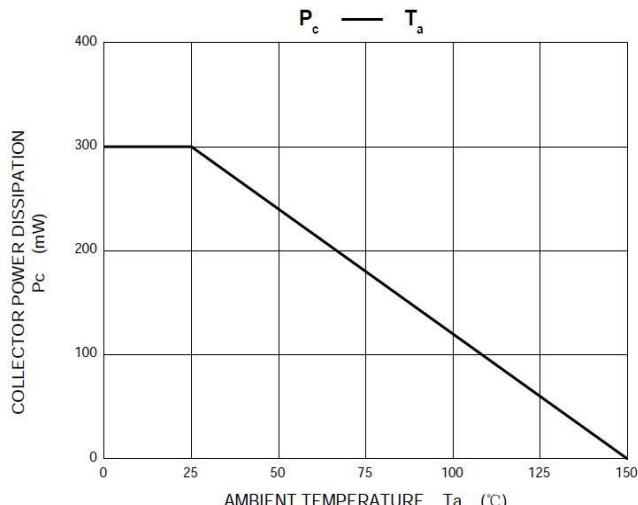
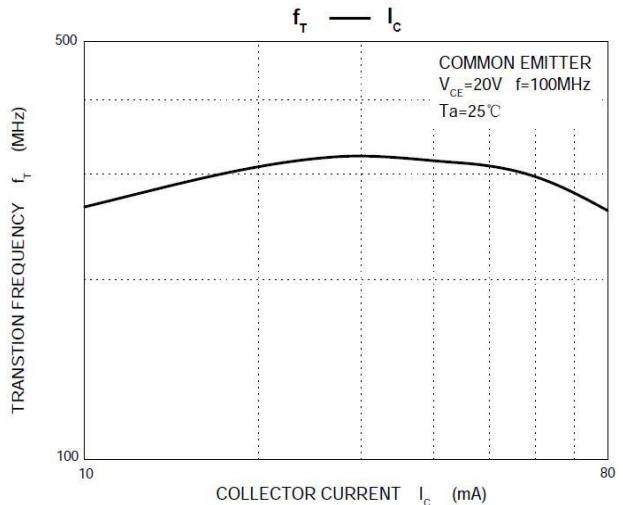
Symbol	Parameter	Test conditions	Min	Typ	Max	Unit
V <sub>(BR)CBO</sub>	Collector-base breakdown voltage	I <sub>C</sub> =10μA, I <sub>E</sub> =0	75	--	--	V
V <sub>(BR)CEO</sub> *	Collector-emitter breakdown voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0	40	--	--	V
V <sub>(BR)EBO</sub>	Emitter-base breakdown voltage	I <sub>E</sub> =10μA, I <sub>C</sub> =0	6	--	--	V
I <sub>CBO</sub>	Collector cut-off current	V <sub>CB</sub> =60V, I <sub>E</sub> =0	--	--	0.01	μA
I <sub>CEX</sub>	Collector cut-off current	V <sub>CE</sub> =30V, V <sub>EB(off)</sub> =3V	--	--	0.01	μA
I <sub>EBO</sub>	Emitter cut-off current	V <sub>EB</sub> = 3V, I <sub>C</sub> =0	--	--	0.1	μA
h <sub>FE1</sub> *	DC current gain	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	100	--	300	
h <sub>FE2</sub> *		V <sub>CE</sub> =10V, I <sub>C</sub> =0.1mA	40	--	--	
h <sub>FE3</sub> *		V <sub>CE</sub> =10V, I <sub>C</sub> =500mA	42	--	--	
V <sub>CE(sat)</sub> *	Collector-emitter saturation voltage	I <sub>C</sub> =500mA I <sub>B</sub> =50mA I <sub>C</sub> =150mA I <sub>B</sub> =15mA	--	--	1 0.3	V
V <sub>BE(sat)</sub> *	Base-emitter saturation voltage	I <sub>C</sub> =500mA I <sub>B</sub> =50mA I <sub>C</sub> =150mA I <sub>B</sub> =19mA	--	--	2 1.2	V
f <sub>T</sub>	Transition frequency	V <sub>CE</sub> = 20V, I <sub>C</sub> =20mA, f=100MHz	300	--	--	MHz
t <sub>d</sub>	Delay time	V <sub>CC</sub> =30V, V <sub>BE(off)</sub> =-0.5V	--	--	10	ns
t <sub>r</sub>	Rise time		--	--	25	ns
t <sub>s</sub>	Storage time	V <sub>CC</sub> =30V, I <sub>C</sub> =150mA, I <sub>B1</sub> =I <sub>B2</sub> =15mA	--	--	225	ns
t <sub>f</sub>	Fall time		--	--	60	ns

## Classification Of h<sub>FE(1)</sub>

Rank	L	H
Range	100-200	200-300
Marking	1P	

## Typical Operating Characteristics

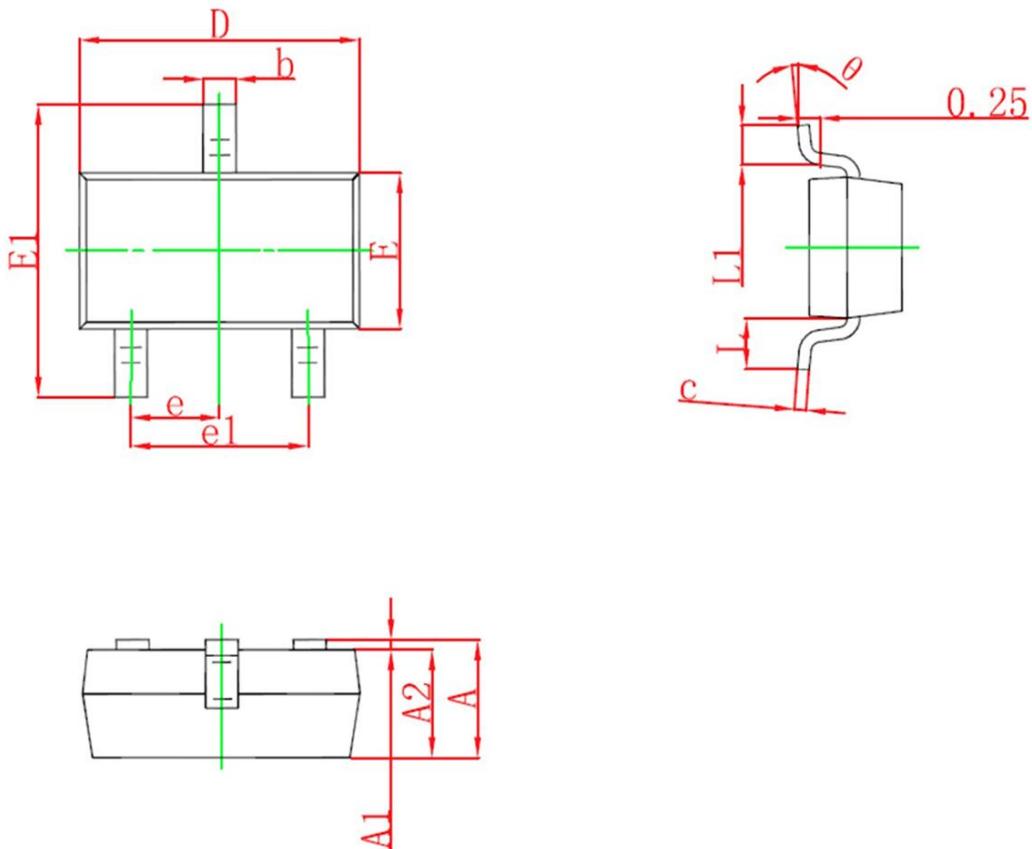




### Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MMBT2222A	SOT-23	1P	3,000	45,000	180,000	7"reel

## SOT-23 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E1	2.250	2.550	0.088	0.100
E	1.200	1.400	0.047	0.055
e	0.950TYP		0.037TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°